

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	65379	"438"/\$.ccls.	US-PGPUB; USPAT	OR	OFF	2004/03/31 19:04
S2	0	semiconductor or ic or "integrated circuit" or microelectronic	US-PGPUB; USPAT	OR	OFF	2003/05/29 17:11
S3	47969	"gate oxide" or "gate dielectric" or "gate insulator"	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:02
S4	1571946	source or drain or "source/drain"	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:03
S5	3884	dmos or "double diffused"	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:03
S6	16897	S3 with S4	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:03
S7	1073	S6 and S5	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:05
S8	3073144	after or subsequent	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:05
S9	1478	S6 with S8	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:05
S10	1907729	before	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:05
S11	3316990	S8 or S10	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:05
S12	2540449	prior	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:06
S13	3749146	S11 or S12	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:06
S14	2012	S6 with S13	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:07
S15	130	S14 and S5	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:11
S16	1	("6380004").PN.	US-PGPUB; USPAT	OR	OFF	2005/05/19 17:11